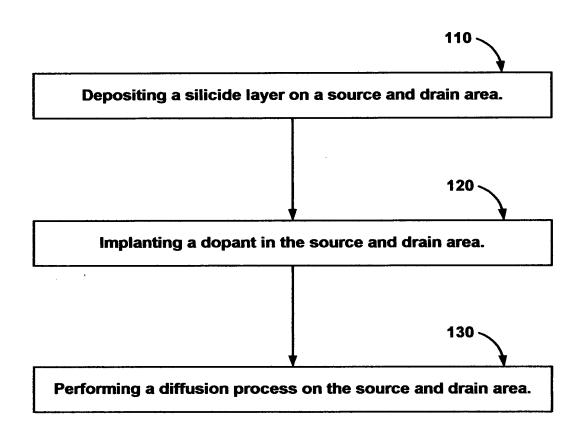
OCT 1 3 2004

TITLE: "A FLASH MEMORY CELL DRAIN AND SOURCE FABRICATION SYSTEM AND METHOD"

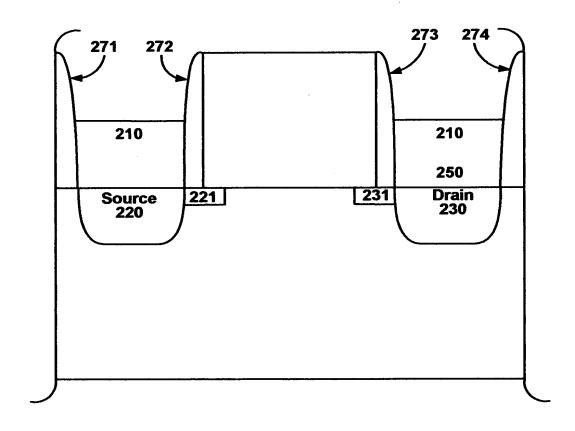
INVENTOR (S): Shenqing Fang Attorney Docket #: AMD-H0634

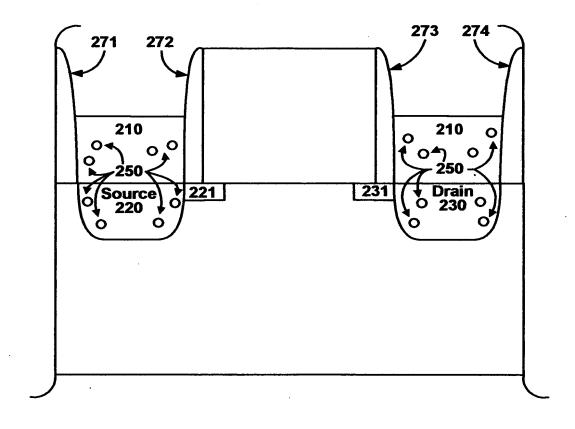
1/6

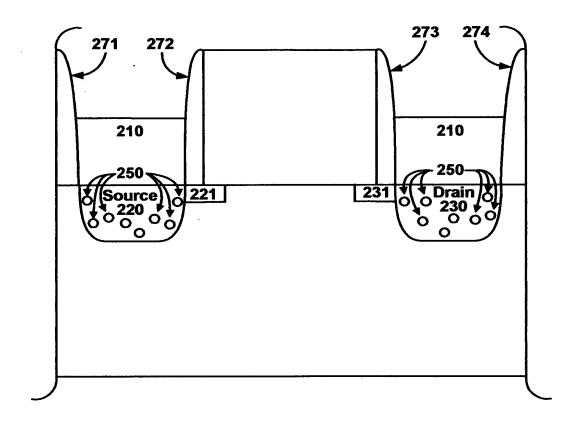
<u>100</u>



1 + 1 × × ×







300

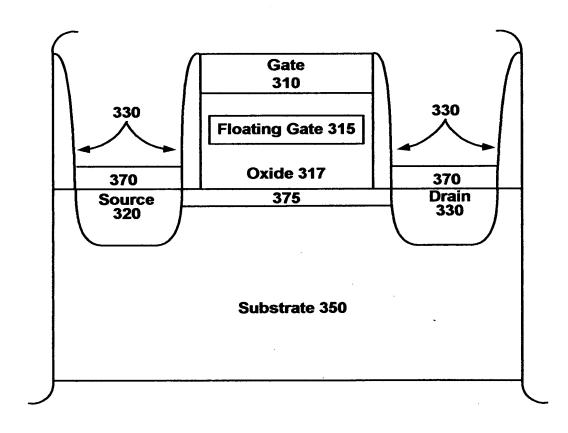


FIG. 3

400

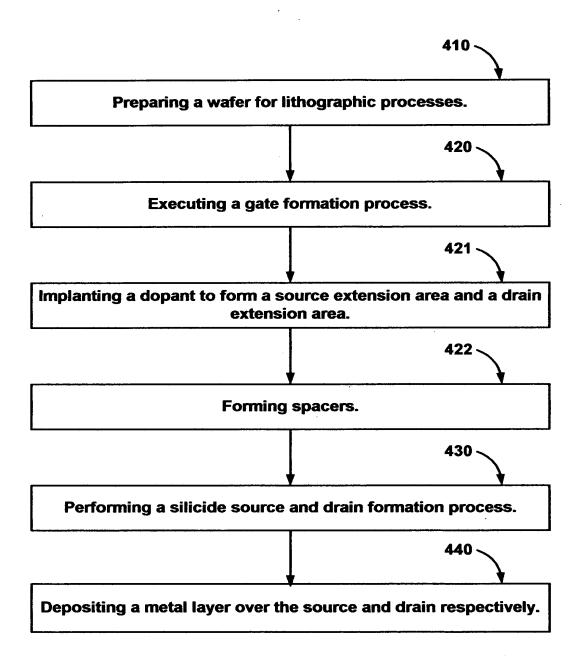


FIG. 4